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ASSP

BIPOLAR

1A Motor Drive IC for Motor Applications

MB3853

DESCRIPTION

The FUJITSU MB3853 is a motor drive IC with two power driver channels capable of sink/source operation, for use in two-channel independent operation or H-type drive operation.

The control system and output system have independent power supplies, allowing the control system to be set to low-voltage operation to conserve power.

Protective circuits are provided for temperature, overvoltage, and overload current, with an open collector type monitoring terminal.

The MB3853 is designed for use with motors in AV products, office automation products, or cameras, and is also an ideal IC for use in automated vending equipment and other unmanned operating devices.

■ FEATURES

- Circuit configuration
 Two sets of built-in control circuits and power circuits

 Built-in fly-back diode
- Functions

Can drive two motors independently or in H-type drive configurations Built-in inhibitor function

■ PACKAGE (Continued)

Plastic SIP, 9 pins

(SIP-9P-M02)



(Continued)

• Input/output terminals

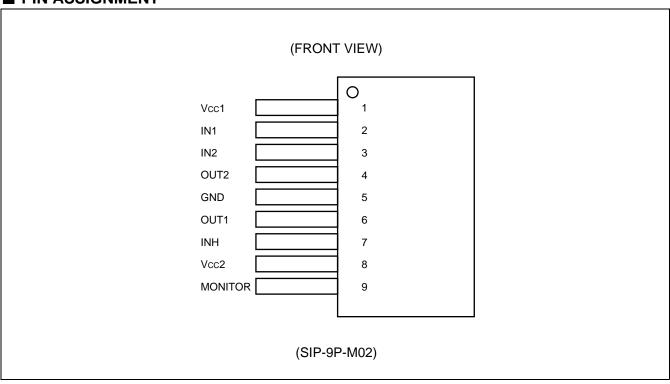
Power supply terminals: Independent control system supply terminal and output system supply terminal

Control terminals: TTL level/CMOS level compatible

Monitor terminal: Open collector type

• Space-saving package (SIP9)

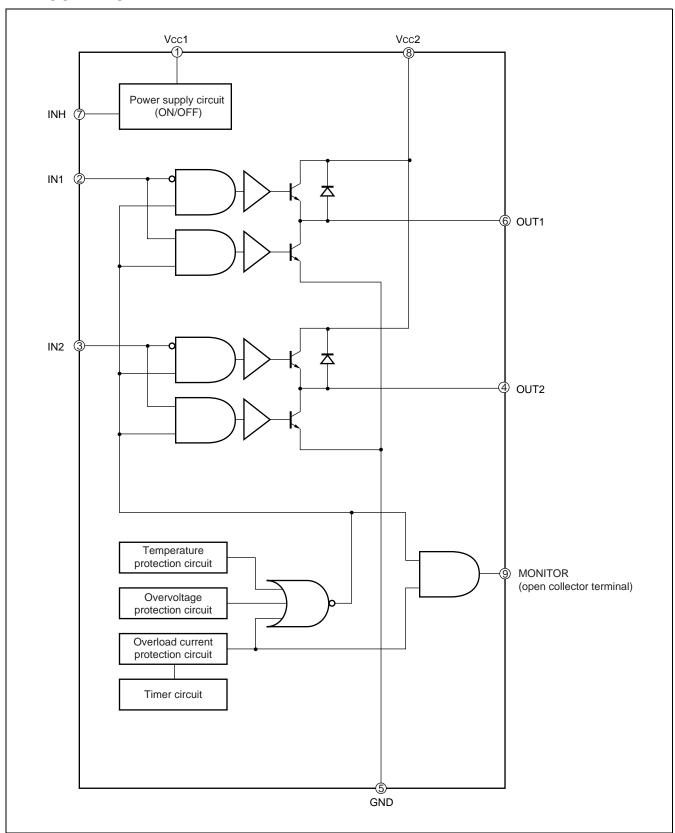
■ PIN ASSIGNMENT



■ PIN DESCRIPTION

Pin no.	Symbol	I/O	Description
1	Vcc1	_	Control system power supply terminal
2	IN1	I	Load control signal input terminal 1
3	IN2	I	Load control signal input terminal 2
4	OUT2	0	Load control output terminal 2
5	GND	_	Ground terminal
6	OUT1	0	Load control output terminal 1
7	INH	I	Inhibitor signal input terminal
8	Vcc2	_	Output system power supply terminal
9	MONITOR	0	Protective circuit motor signal output terminal (open collector type terminal)

■ BLOCK DIAGRAM

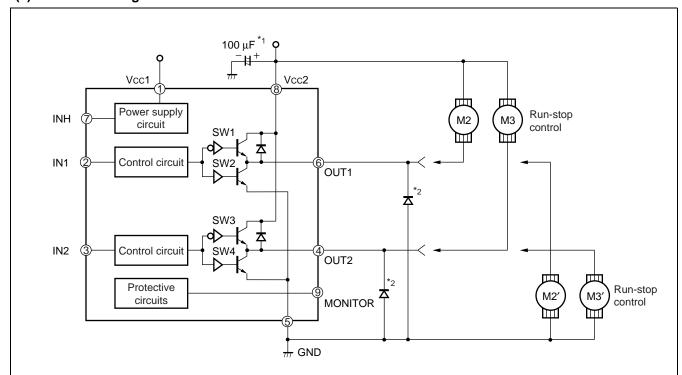


■ FUNCTIONAL DESCRIPTION

The MB3853 provides two methods for controlling motors. The IC can be connected to two motors and drive each motor independently, or connected to one motor in an H-type connection and drive the motor in forward and reverse directions.

1. Sample connection to 2 motors for run-stop control.

(1) Connection diagram



- *1 : The capacitor should be placed close to the IC terminal.
- *2 : When using the M2' and M3' terminals, ensure that the OUT1 terminal (pin 6) voltage and OUT2 terminal (pin 4) voltage do not fall below –0.3 V by connecting the OUT1 and OUT2 terminals to ground through a Shottky barrier diode.

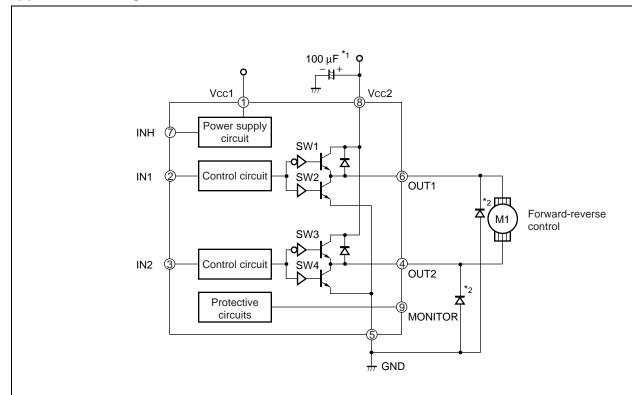
(2) Table of Functions

Mode	Input voltage level			Output terminals		Motor operating mode			
Mode	INH	IN1	IN2	OUT1	OUT2	M2	М3	M2'	M3'
Inhibit mode	"L"	×	×	•	FF pedance)	Continuous operation			
Mode (1)		"L"	"L"	"H"	"H"	Brake	Brake	Run	Run
Mode (2)	- "H"	"L"	"H"	"H"	"L"	Brake	Run	Run	Brake
Mode (3)]	"H"	"L"	"L"	"H"	Run	Brake	Brake	Run
Mode (4)		"H"	"H"	"L"	"L"	Run	Run	Brake	Brake

imes : May be either "H" or "L" level

2. Sample connection to 1 motor for forward-reverse control

(1) Connection diagram



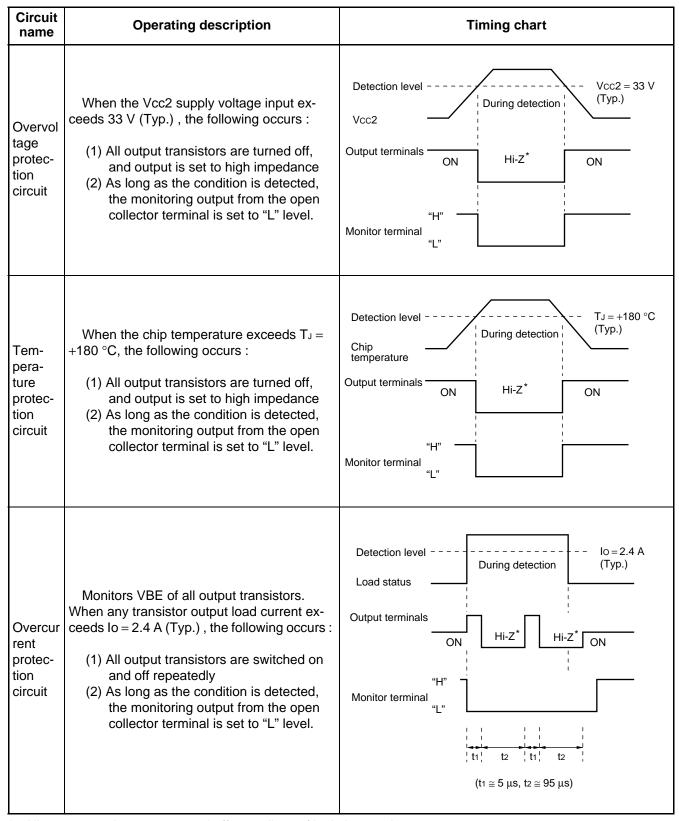
- *1: The capacitor should be placed close to the IC terminal.
- *2: Ensure that the OUT1 terminal (pin 6) voltage and OUT2 terminal (pin 4) voltage do not fall below -0.3 V by connecting the OUT1 and OUT2 terminals to ground through a Shot key barrier diode.

(2) Table of functions

Mode	Input voltage level			Output t	erminals	Motor mode	
Ivioue	INH	IN1	IN2	OUT1	OUT2	Wiotor mode	
Inhibit mode	"["	×	×	OFF (High impedance)		Continuous operation	
Mode (1)		"L"	"L"	"H" "H"		Brake	
Mode (2)	"H"	"L"	"H"	"H" "L"		Forward (reverse)	
Mode (3)	11	"H"	"L"	"L"	"L" "H" Reverse (t		
Mode (4)		"H"	"H"	"L" "L"		Brake	

 $\times\,\,$: May be either "H" or "L" level

■ PROTECTIVE CIRCUITS



^{* :} All output transistors are turned off regardless of logic input voltage.

■ ABSOLUTE MAXIMUM RATINGS

(GND = 0 V)

Parameter	Symbol	Condition	Rat	Unit	
Farameter	Symbol		Min.	Min. Max.	
Supply voltage	Vcc1	_	_	30	V
Supply voltage	Vcc2	_		30	V
Surge voltage	Vcc (S)	$t_r \geq 1 \text{ ms, } t_s \leq 200 \text{ ms}$		60	V
Output current	lo	10 ms or less per termi- nal	_	1.8	А
Power consumption	P□	Tc ≤ +75 °C		18	W
Operating temperature	Tc	_	-40	+85	°C
Storage temperature	Tstg	_	-55	+150	°C

WARNING: Semiconductor devices can be permanently damaged by application of stress (voltage, current, temperature, etc.) in excess of absolute maximum ratings. Do not exceed these ratings.

■ RECOMMENDED OPERATING CONDITIONS

(GND = 0 V)

Doromotor	Symbol	Conditions		l lmi4			
Parameter	Symbol	Conditions	Min.	Тур.	Max.	Unit	
Supply voltage	Vcc1	Control system supply voltage	4.5	5	30	V	
Supply voltage	Vcc2	Output system supply voltage	_	24	30	V	
"H" level input voltage	Vih	IN1, IN2, INH terminals	2.0	_	Vcc1 + 0.3	V	
"L" level input voltage	VIL	TINT, INZ, INFI LEITHINAIS	-0.3	_	0.8	V	
Operating temperature Tc —		0	25	70	°C		

WARNING: The recommended operating conditions are required in order to ensure the normal operation of the semiconductor device. All of the device's electrical characteristics are warranted when the device is operated within these ranges.

Always use semiconductor devices within their recommended operating condition ranges. Operation outside these ranges may adversely affect reliability and could result in device failure.

No warranty is made with respect to uses, operating conditions, or combinations not represented on the data sheet. Users considering application outside the listed conditions are advised to contact their FUJITSU representatives beforehand.

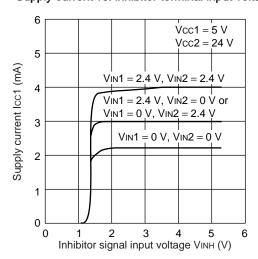
■ ELECTRICAL CHARACTERISTICS

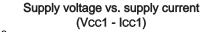
(Tc = +25 °C, GND = 0 V, Vcc1 = 5 V, Vcc2 = 24 V)

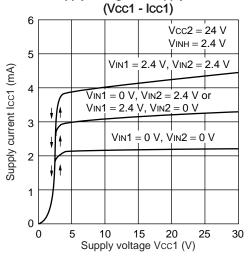
	aramatar.	Symbol	Conditions	Values			Unit
	Parameter		Conditions	Min.	Тур.	Max.	Unit
"L" level input current		lı∟	Vı∟ = 0.4 V	_		100	μΑ
"H" level input currer	nt	Іін	V _{IH} = 2.4 V	_	_	100	μΑ
"L" level output curre	ent	Vol	Io = 1 A	_	1.0	1.4	V
"H" level output curre	ent	Vон	Io = −1 A	22.5	23.0		V
Diode forward voltag	ie .	VF	Io = 1.8 A	_	2.2		V
Overcurrent detection	n current	Ics	_	1.8	2.4	3.5	Α
Overcurrent detectio	n voltage	Vsp	_	30.5	33.0	35.5	V
"L" level monitoring of	output voltage	Vol	lo = 1 mA	_	0.2	0.4	V
"H" level monitoring	output current	Іон	Vон = 24 V	_	_	0.01	mA
			IN1 = IN2 = "H"	_	3.7	7.4	mA
		Icc1	IN1/IN2 = "H/L"	_	2.8	5.6	mA
			IN1 = IN2 = "L"		1.9	3.8	mA
Supply current			IN1 = IN2 = "H"	_	_	1.0	mA
		Icc2	IN1/IN2 = "H/L"	_	13	20	mA
			IN1 = IN2 = "L"		26	40	mA
		Icc0	Icc1 + Icc2 INH = "L"	_	_	1.0	mA
Package thermal res	sistance	Ө J-с	Infinite heat dissipation		4	_	°C/W
	OUT1 or OUT2 nor to recipal	P□	Io = 1 A		1.2	_	W
Power consumption	OUT1 or OUT2, per terminal		lo = 0 mA (braking)		300	_	mW
	In H-type drive configuration		Io = 1 A		2.4		W

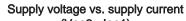
■ TYPICAL CHARACTERISTIC

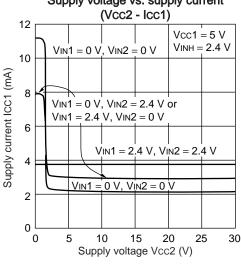
Supply current vs. inhibitor terminal input voltage



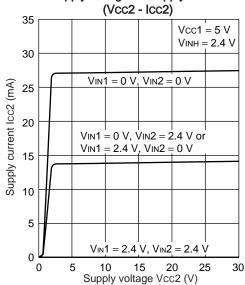


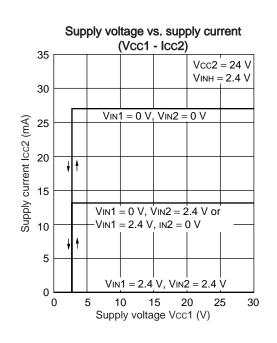


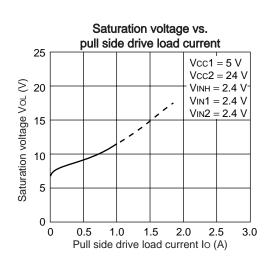


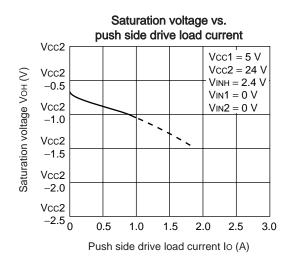


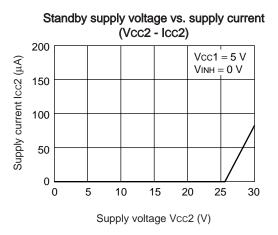
Supply voltage vs. supply current

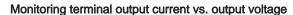


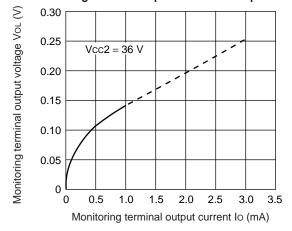




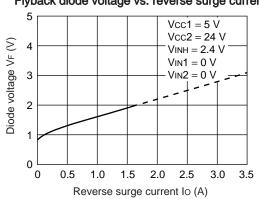




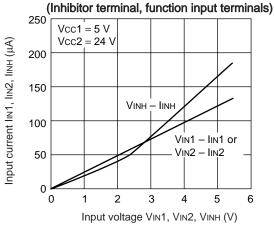




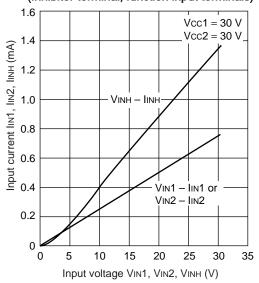
Flyback diode voltage vs. reverse surge current



Input current vs. input voltage (Inhibitor terminal, function input terminals)

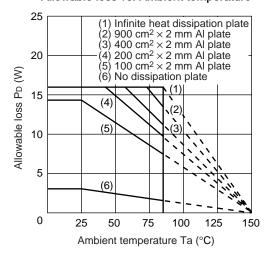


Input current vs. voltage characteristics at maximum applied voltage (Inhibitor terminal, function input terminals)

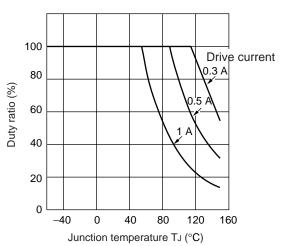


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Allowable loss vs. Ambient temperature



Junction temperature vs. duty ratio



- Notes: For stable operation over periods of extended usage, the duty ratio should be kept below the characteristic curve.
 - Junction temperature should be maintained at $T_J \le +150$ °C.

(Tj calculation)

 $T_J = T_C + \Delta T$

 $\Delta T = 4 (^{\circ}C/W) \times P_{DI}$

 $P_{DI} = V_{CC} \times I_{CC} + \Delta V_{O} \times I_{O}$

 $\Delta V_0 = (V_{CC} - V_{OH}) + V_{OL}$

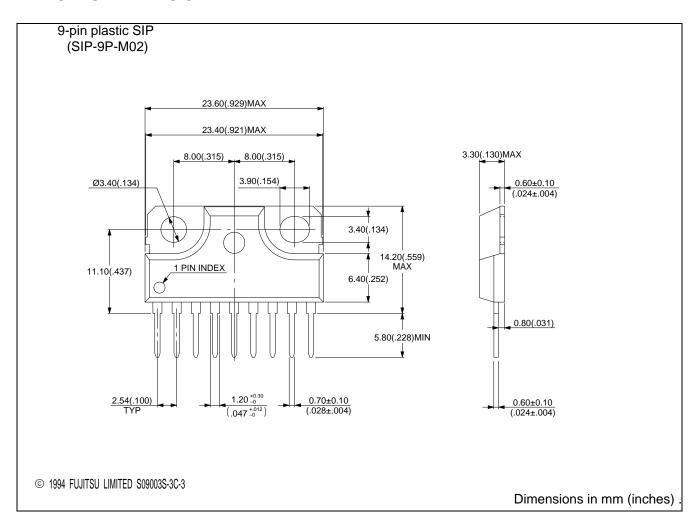
 T_{C} : case temperature, ΔT : difference between case and junction temperature

P_{DI}: IC power consumption (W)

■ ORDERING INFORMATION

Part Number	Package	Remarks
MB3853PS	Plastic SIP, 9 pins (SIP-9P-M02)	

■ PACKAGE DIMENSION



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